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Docket No. 8733-6836

TECHNOLOGY CENTER 2000

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Duck-Kyun CHOI

GAU: 2823

SERIAL NO: 09/170,625

EXAMINER: S. Hawranek

FILING DATE: October 13, 1998

FOR: Method For Fabricating a Thin Film Transistor

DECLARATION UNDER 37 C.F.R. § 1.131

I, Duck-Kyun Choi, the named inventor of the above-referenced application, hereby declare the following:

1. I am one of the co-authors of the article entitled "I-V Characteristics Of Poly-Silicon Thin Film Transistors By Field-Aided Lateral Crystallization (FALC)" (the "Article"), which indicates that it was published at the 5th International Conference on VLSI and CAD on October 13 - 15, 1997 in Seoul, Korea.

2. The other authors listed on the Article, Kyung-Sub Song, Seung-Ik Jun, and Sang-Hyun Park, are listed as authors solely because they performed work under my direction in connection with the preparation of the Article.

3. I believe that I am the sole inventor of the subject matter claimed in the above-referenced application.

The foregoing statements are made with the knowledge that willful false statements and

the like are punishable by fine or imprisonment, or both, under 18 U.S.C. § 1001 and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

Date: Mar. 8, 2000

Duck Kyun Choi
Duck-Kyun Choi

Witnesses:

Date: Mar. 8, 2000

Printed Name: Jae-Bok Lee

Jae-Bok Lee

Date: Mar. 8, 2000

Printed Name: Chul-Ho Kim

Chul-Ho Kim